


## TRANSMITTAL

Electronic Version v1.1

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Title of Invention	Method of Selective Deposition of Heavily Doped Epitaxial SiGe		
Application Number :	10/683937		
Date :	2003-10-10		
First Named Applicant:	Kim Yihwan		
Confirmation Number:	2191		
Attorney Docket Number:	AMAT8539TSGEPIRKK		
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Submitted By:		Elec. Sign.	Sign. Capacity
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Documents being submitted:	Files
us-ids	AMAT8539TSGEPIRKK-usidst.xml us-ids.dtd us-ids.xsl
Comments	